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Jameco Part Number 885671

2N6515, 2N6517, 2N6520

High Voltage Transistors

NPN and PNP

Features

- Voltage and Current are Negative for PNP Transistors
- Pb-Free Package is Available*

MAXIMUM RATINGS

Rating	Symbol	2N6515	2N6517 2N6520	Unit
Collector – Emitter Voltage	V_{CEO}	250	350	Vdc
Collector – Base Voltage	V_{CBO}	250	350	Vdc
Emitter – Base Voltage 2N6515, 2N6516, 2N6517 2N6519, 2N6520	V_{EBO}	6.0 5.0		Vdc
Base Current	I_B	250		mAdc
Collector Current – Continuous	I_C	500		mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0		mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12		Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150		$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

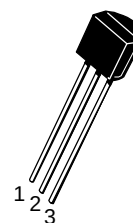
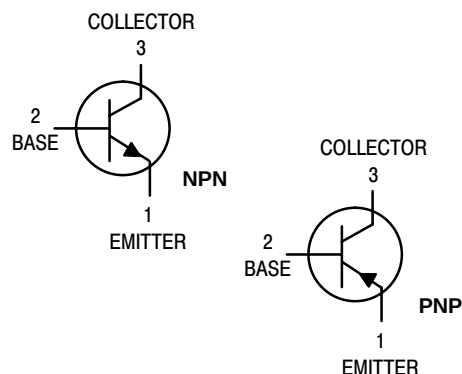
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C/W}$



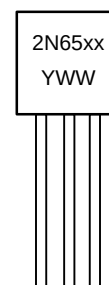
ON Semiconductor®

<http://onsemi.com>



TO-92
CASE 29
STYLE 1

MARKING DIAGRAM



Y = Year
WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

2N6515, 2N6517, 2N6520

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage (Note 1) ($I_C = 1.0\text{ mAdc}$, $I_B = 0$)	$V_{(BR)CEO}$	250 350	– –	Vdc
Collector–Base Breakdown Voltage ($I_C = 100\text{ }\mu\text{Adc}$, $I_E = 0$)	$V_{(BR)CBO}$	250 350	– –	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10\text{ }\mu\text{Adc}$, $I_C = 0$)	$V_{(BR)EBO}$	6.0 5.0	– –	Vdc
Collector Cutoff Current ($V_{CB} = 150\text{ Vdc}$, $I_E = 0$) ($V_{CB} = 250\text{ Vdc}$, $I_E = 0$)	I_{CBO}	– –	50 50	nAdc
Emitter Cutoff Current ($V_{EB} = 5.0\text{ Vdc}$, $I_C = 0$) ($V_{EB} = 4.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	– –	50 50	nAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain ($I_C = 1.0\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$) ($I_C = 10\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$) ($I_C = 30\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$) ($I_C = 50\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$) ($I_C = 100\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$)	h_{FE}	35 20 50 30 50 30 45 20 25 15	– – – – 300 200 220 200 – –	–
Collector–Emitter Saturation Voltage ($I_C = 10\text{ mAdc}$, $I_B = 1.0\text{ mAdc}$) ($I_C = 20\text{ mAdc}$, $I_B = 2.0\text{ mAdc}$) ($I_C = 30\text{ mAdc}$, $I_B = 3.0\text{ mAdc}$) ($I_C = 50\text{ mAdc}$, $I_B = 5.0\text{ mAdc}$)	$V_{CE(sat)}$	– – – –	0.30 0.35 0.50 1.0	Vdc
Base–Emitter Saturation Voltage ($I_C = 10\text{ mAdc}$, $I_B = 1.0\text{ mAdc}$) ($I_C = 20\text{ mAdc}$, $I_B = 2.0\text{ mAdc}$) ($I_C = 30\text{ mAdc}$, $I_B = 3.0\text{ mAdc}$)	$V_{BE(sat)}$	– – –	0.75 0.85 0.90	Vdc
Base–Emitter On Voltage ($I_C = 100\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$)	$V_{BE(on)}$	–	2.0	Vdc

1. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

2N6515, 2N6517, 2N6520

SMALL-SIGNAL CHARACTERISTICS

Current-Gain – Bandwidth Product (Note 1) ($I_C = 10 \text{ mA}$, $V_{CE} = 20 \text{ Vdc}$, $f = 20 \text{ MHz}$)	f_T	40	200	MHz
Collector-Base Capacitance ($V_{CB} = 20 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	C_{cb}	–	6.0	pF
Emitter-Base Capacitance ($V_{EB} = 0.5 \text{ Vdc}$, $I_C = 0$, $f = 1.0 \text{ MHz}$)	C_{eb}	– –	80 100	pF

SWITCHING CHARACTERISTICS

Turn-On Time ($V_{CC} = 100 \text{ Vdc}$, $V_{BE(off)} = 2.0 \text{ Vdc}$, $I_C = 50 \text{ mA}$, $I_{B1} = 10 \text{ mA}$)	t_{on}	–	200	μs
Turn-Off Time ($V_{CC} = 100 \text{ Vdc}$, $I_C = 50 \text{ mA}$, $I_{B1} = I_{B2} = 10 \text{ mA}$)	t_{off}	–	3.5	μs

1. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

ORDERING INFORMATION

Device	Package	Shipping [†]
2N6515	TO-92	5000 Unit / Bulk
2N6515RLRM	TO-92	2000 Tape & Ammo Box
2N6517	TO-92	5000 Unit / Bulk
2N6517RLRA	TO-92	2000 Tape & Reel
2N6517RLRP	TO-92	2000 Tape & Ammo Box
2N6520RLRA	TO-92	2000 Tape & Reel
2N6520RLRAG	TO-92 (Pb-Free)	2000 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

2N6515, 2N6517, 2N6520

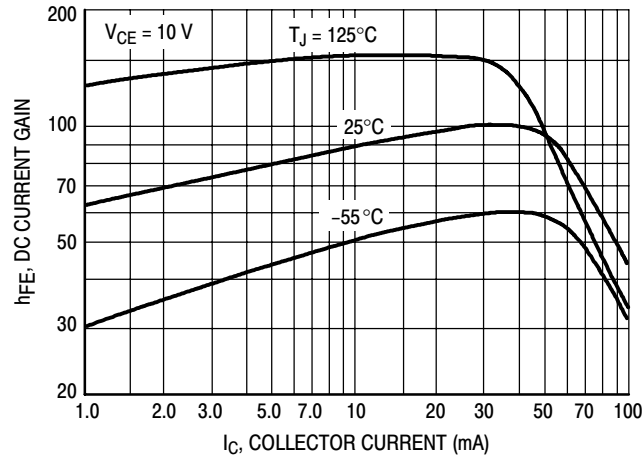


Figure 1. DC Current Gain
NPN 2N6515

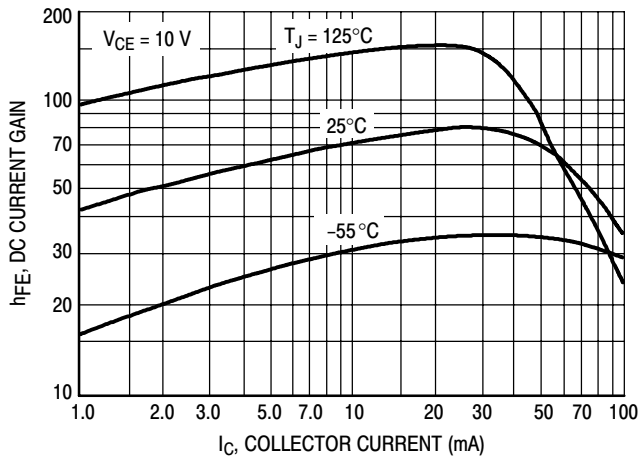


Figure 2. DC Current Gain
NPN 2N6517

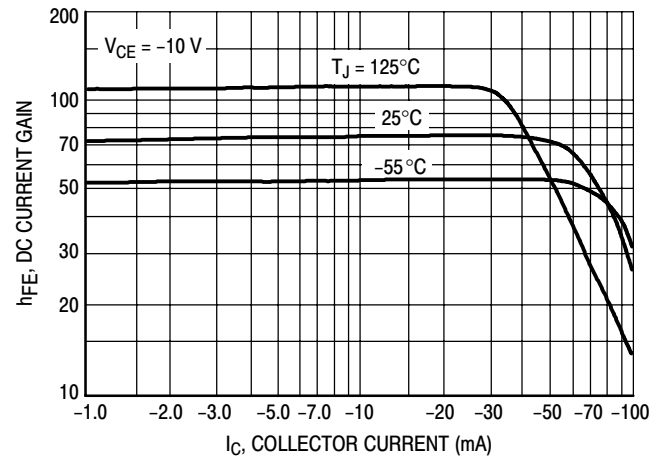


Figure 3. DC Current Gain
PNP 2N6520

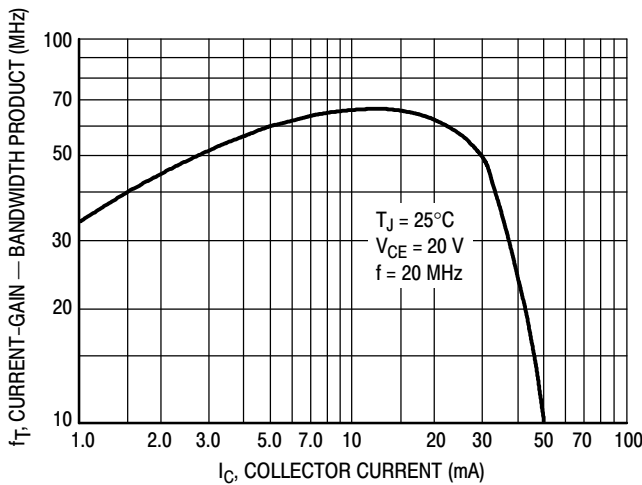


Figure 4. Current-Gain - Bandwidth Product
NPN 2N6515, 2N6517

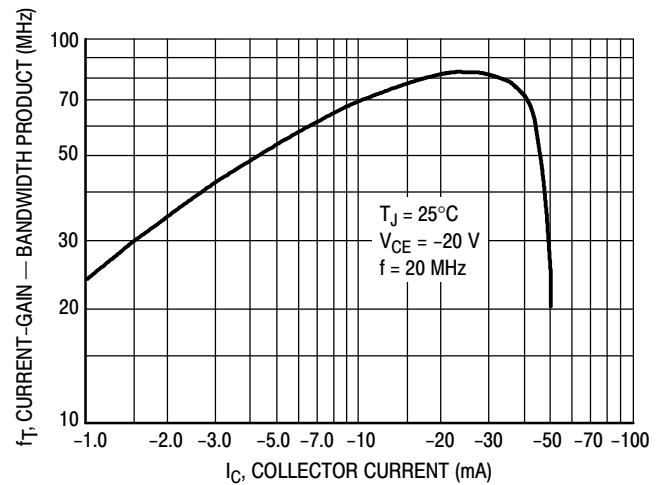


Figure 5. Current-Gain - Bandwidth Product
PNP 2N6520

2N6515, 2N6517, 2N6520

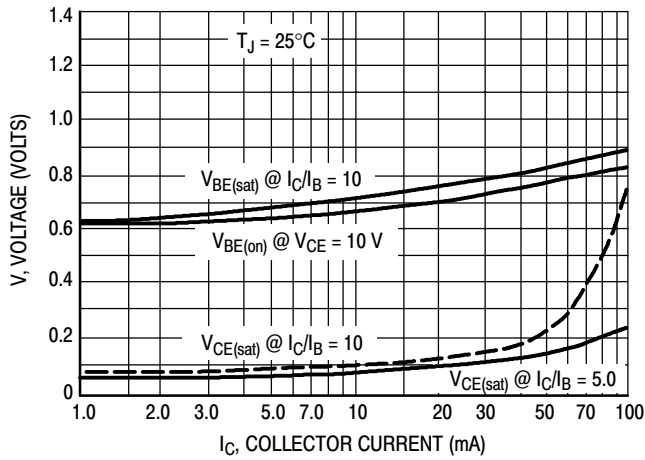


Figure 6. "On" Voltages
NPN 2N6515, 2N6517

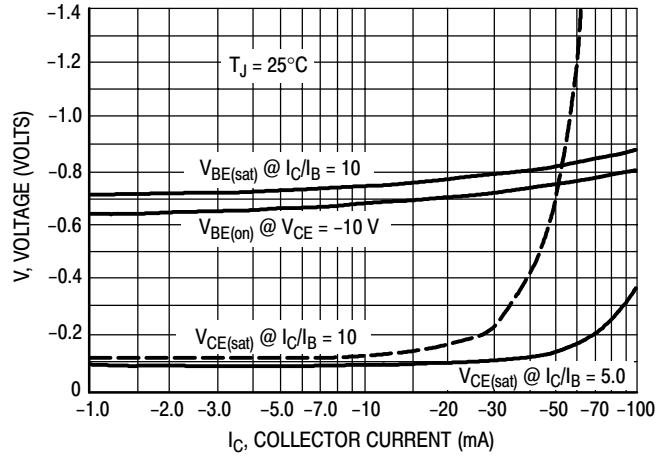


Figure 7. "On" Voltages
PNP 2N6520

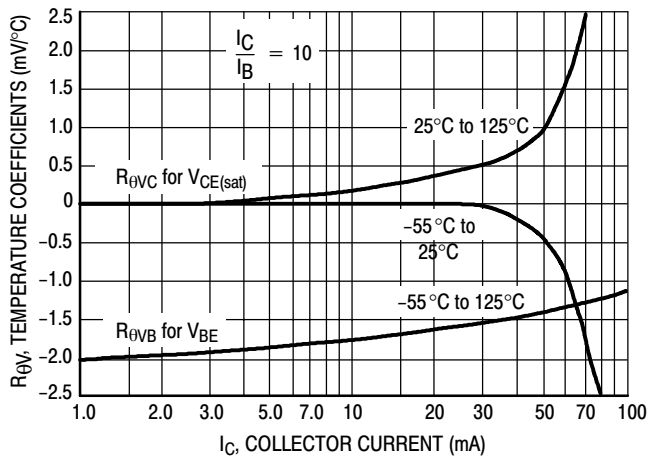


Figure 8. Temperature Coefficients
NPN 2N6515, 2N6517

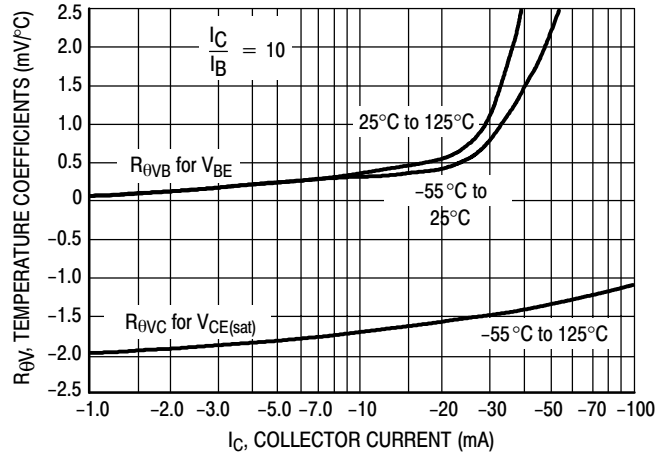


Figure 9. Temperature Coefficients
PNP 2N6520

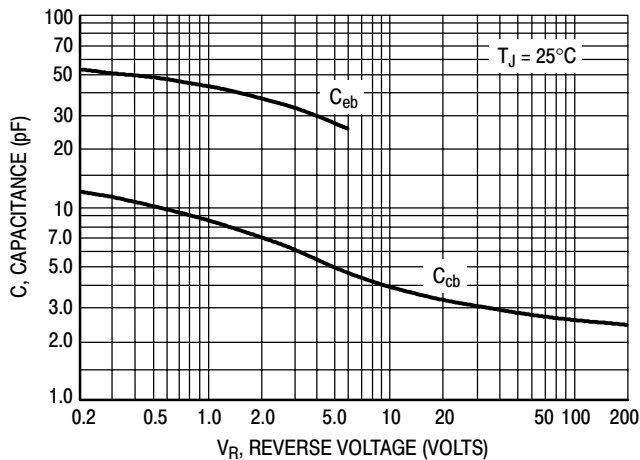


Figure 10. Capacitance
NPN 2N6515, 2N6517

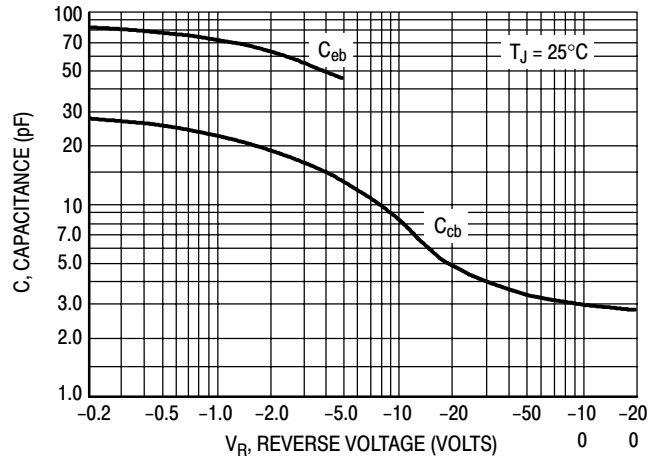


Figure 11. Capacitance
PNP 2N6520

2N6515, 2N6517, 2N6520

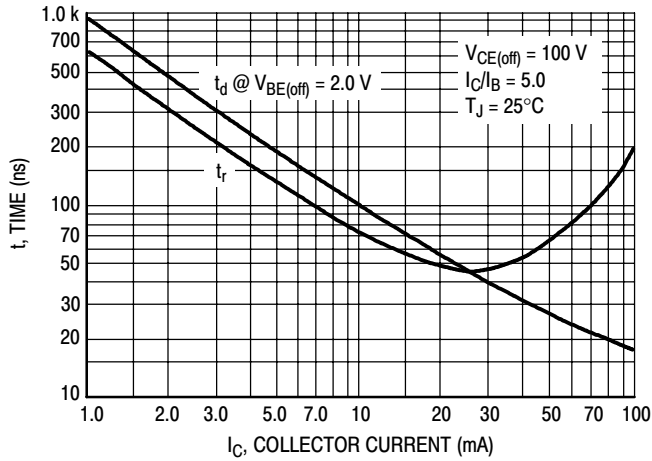


Figure 12. Turn-On Time
NPN 2N6515, 2N6517

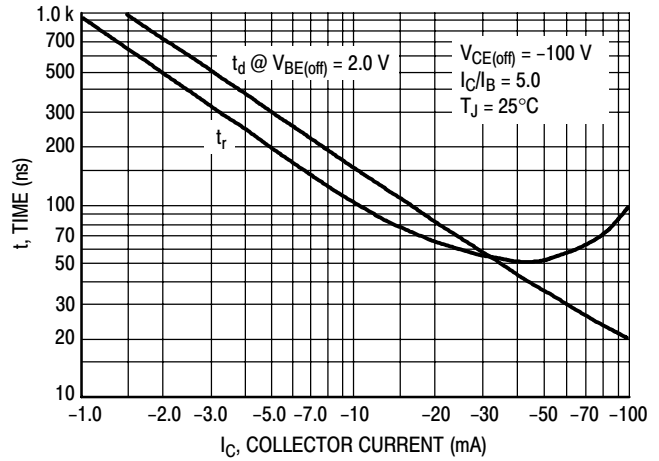


Figure 13. Turn-On Time
PNP 2N6520

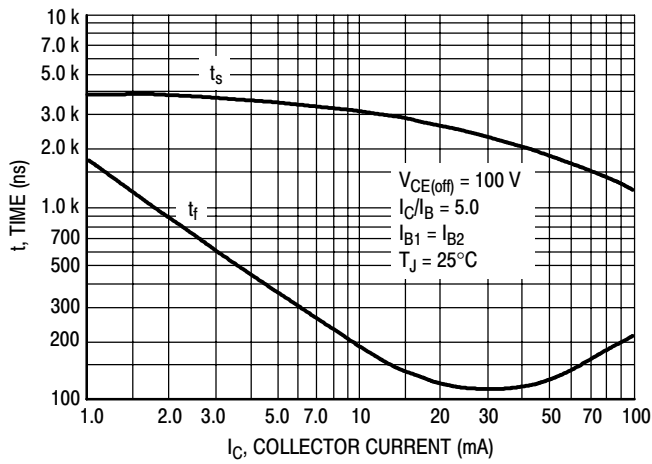


Figure 14. Turn-Off Time
NPN 2N6515, 2N6517

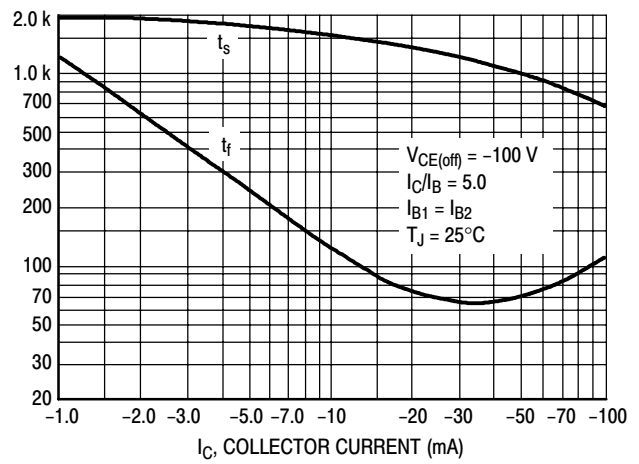


Figure 15. Turn-Off Time
PNP 2N6520

2N6515, 2N6517, 2N6520

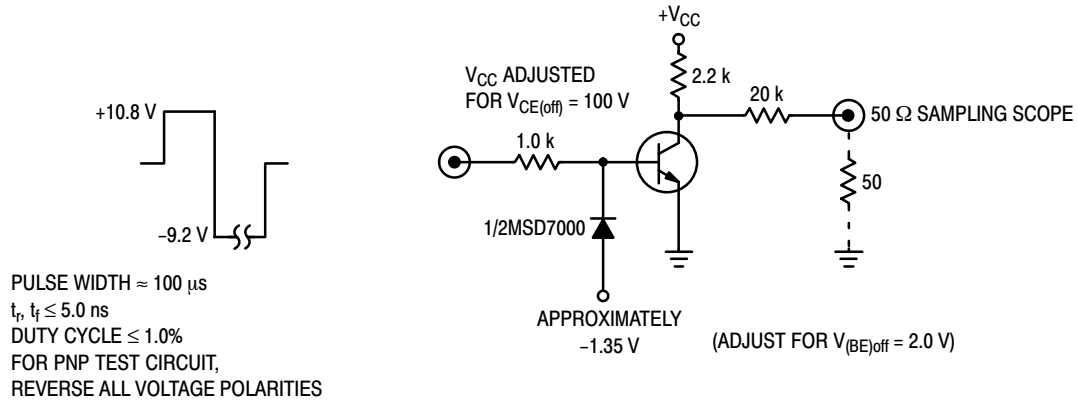


Figure 16. Switching Time Test Circuit

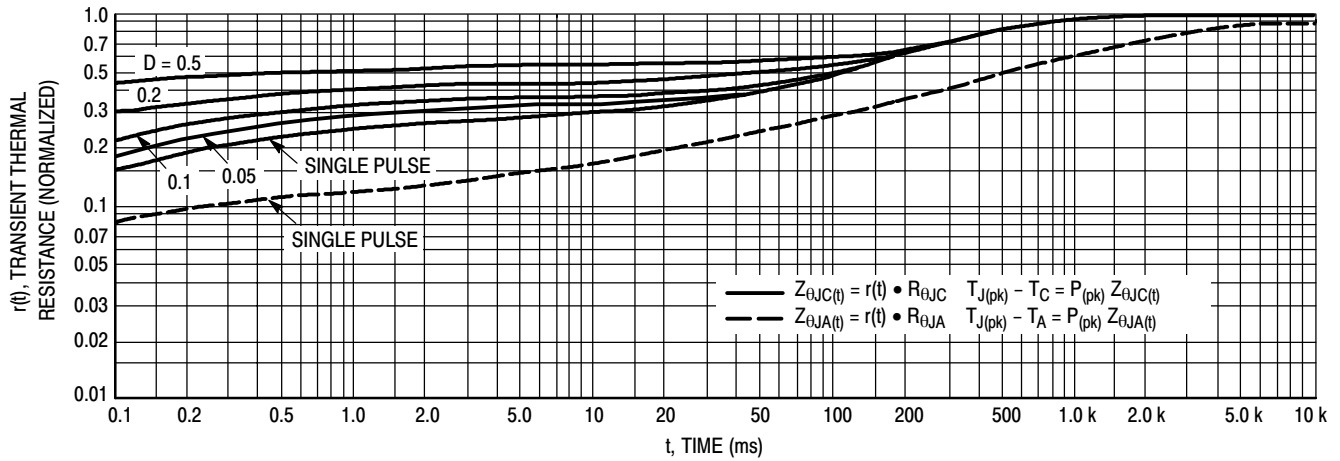


Figure 17. Thermal Response

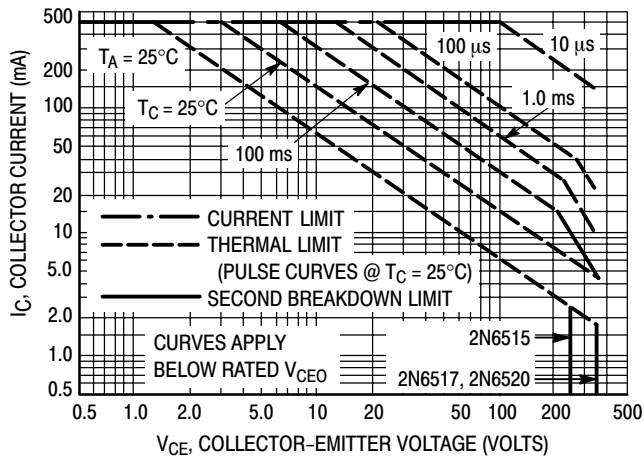
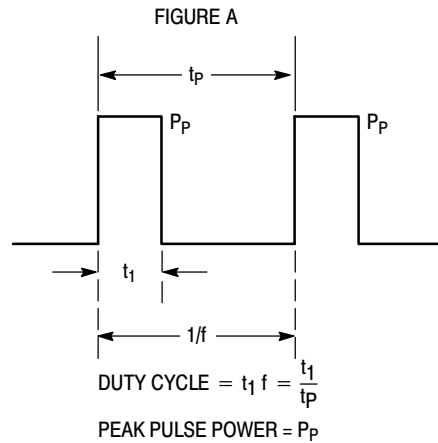


Figure 18. Active Region Safe Operating Area

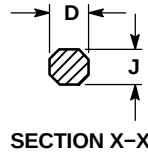
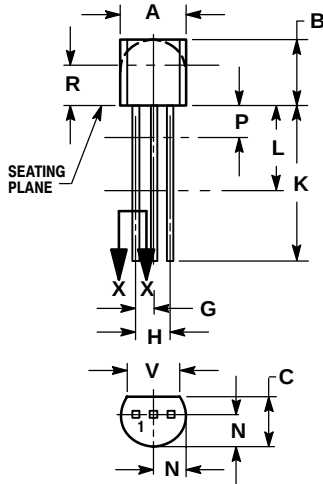


Design Note: Use of Transient Thermal Resistance Data

2N6515, 2N6517, 2N6520

PACKAGE DIMENSIONS

TO-92
CASE 29-11
ISSUE AL



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 1:

- PIN 1. EMITTER
- BASE
- COLLECTOR

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